

20.0 A Single-Phase Silicon Bridge Rectifier

Rectifier Reverse Voltage 50 to 1000V

Features

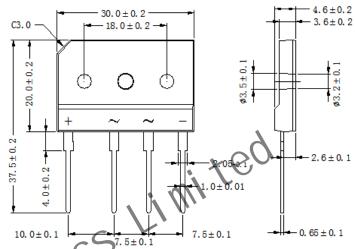
- · Ideal for printed circuit board mounting
- This series is UL listed under the Recognized Component Index
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Built-in printed circuit board stand-offs
- High case dielectric strength
- High temperature soldering guaranteed 260℃/5 seconds at 5 lbs (2.3kg) tension

Mechanical Data

Case: Reliable low cost construction utilizing molded plastic technique

Terminals: Plated leads solderable per MIL-STD-202,

Method 208 Mounting Position: Any



Dimensions in inches and (milimeters)

Maximum Ratings & Thermal CharacteristicsRating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz. For Capacitive load derate current by 20%

CHARACTERISTICS	SYMBOL	ARDGBJ 20005KX0	ARDGBJ 2001KX0	ARDGBJ 2002KX0	ARDGBJ 2004KX0	ARDGBJ 2006KX0	ARDGBJ 2008KX0	ARDGBJ 2010KX0	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Vottage	VRMS	30	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward (with heatsink Note 2)	Lavo	20.0							А
Rectified Current @ Tc=100℃ (without heatsink)	I(AV) 3.5								
Peak Forward Surage Current	IFSM 240								
8.3ms Single Half Sine-Wave								Α	
Super Imposed on Rated Load (JEDEC Method)									
Maximum Forward Voltage at 10.0A DC	VF	1.1							V
Maximum DC Reverse Current @ TJ=25°C	lo.	10							uA
at Rated DC Blocking Voltage @ TJ=125℃	IR 500								
Typical Thermal Resistance (Note2)	Rejc	1.5							°C/W
Operating Temperature Range	TJ	-55 to +150							$^{\circ}\!\mathbb{C}$
Storage Temperature Range	Тѕтс	-55 to +150							$^{\circ}\!\mathbb{C}$

NOTES: 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2.Device mounted on 300mm*300mm*1.6mm cu plate heatsink.



Rating and Characteristic Curves (TA=25°C Unless otherwise noted)

